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Application Number 09/800,627 Filing Date March 7, 2001 First Named Inventor Koichiro Tanaka, et al.

SEL 245

Art Unit 2822 **Examiner Name** Toniae M. Thomas Attorney Docket Number

#14 INFORMATION DISCLOSURE

STATEMENT BY APPLICANT (Use as many sheets as necessary)

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U. S. PATENT DOCUMENTS Examine **Document Number** Name of Patentee or Publication Date Pages, Columns, Lines, Where Initials* MM-DD-YYYY Applicant of Cited Document Relevant Passages or Relevant Number-Kind Code^{2 (#kno wn)} Figures Appear ^{US-} 5,529,937 TMT 06/25/1996 Zhang et al. ^{US-} 5,681,759 10/28/1997 Zhang US-5,830,784 11/03/1998 Zhang et al. ^{US-} 5,879,974 03/09/1999 Yamazaki. ^{US-} 5,879,977 03/09/1999 Zhang et al. US-5,897,347 04/27/1999 Yamazaki et al. ^{US-} 5.904,770 05/18/1999 Ohtani et al. ^{US-} 5,923,966 07/13/1999 Teramoto et al. ^{US-} 6,071,764 06/06/2000 Zhang et al. ^{US-} 6,077,758 06/20/2000 Zhang et al. US- 6,088,070 07/11/2000 Ohtani et al. ^{US-} 6,160,279 12/12/2000 Zhang et al. 1 US- 2001/0000011 A1 03/15/2001 Zhang et al. US- 6,232,156 B1 05/15/2001 Ohtani et al. US- 6,285,042 B1 09/04/2001 Ohtani et al. ^{US-} 6,312,979 B1 11/06/2001 Jang et al. US- 6,326,226 B1 12/04/2001 Jang et al. ^{US-} 6,335,541 B1 <u>ب</u> 01/01/2002 Ohtani et al. US- 2002/0053670 A1 $\mathsf{TM}\mathsf{T}$ 05/09/2002 Ohtani et al.

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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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Complete if Known Application Number 09/800,627 Filing Date March 7, 2001 First Named Inventor Koichiro Tanaka, et al. Art Unit 2822 Examiner Name Toniae M. Thomas Attorney Docket Number **SEL 245**

Examiner	Cite	Document Number	Publication Date	Name of Patentee or	Pages,C olumns, Lines, Where	
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